NSN 5962-01-239-0413

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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
Programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Terminal Surface Treatment:
Solder
Product Name:
Programmed gate array
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
25.00 nanoseconds access
Memory Device Type:
Pal
Terminal Type And Quantity:
20 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0